NSN 5962-01-353-3061

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N/a



View Online at https://aerobasegroup.com/nsn/5962-01-353-3061

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Body Length:
0.560 inches
Body Width:
Between 0.442 inches and 0.458 inches
Body Height:
Between 0.060 inches and 0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Countermeasures set an/alq-135
Features Provided:
Hermetically sealed and burn in and monolithic and static operation
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
25 input
Case Outline Source And Designator:
C-12 mil-m-38510
Current Rating Per Characteristic:
105.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
45.00 nanoseconds delay
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 leadless
Shelf Life:

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Demilitarization:

No

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